TOSHIBA CMOS Digital Integrated Circuit   Silicon Monolithic

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3-to-8 Line Decoder

The TC7MH138FK is an advanced high speed CMOS 3-to-8 decoder fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 binary select inputs (A, B and C) determine which one of the outputs ($\overline{Y0}$ - $\overline{Y7}$) will go low.

When enable input G1 is held low or either $\overline{G2A}$ or $\overline{G2B}$ is held high, decoding function is inhibited and all outputs go high.

G1, $\overline{G2A}$, and $\overline{G2B}$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.
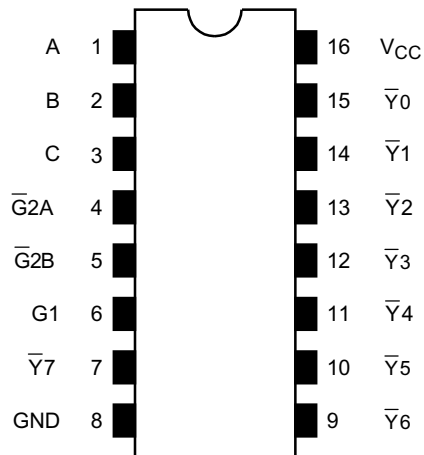

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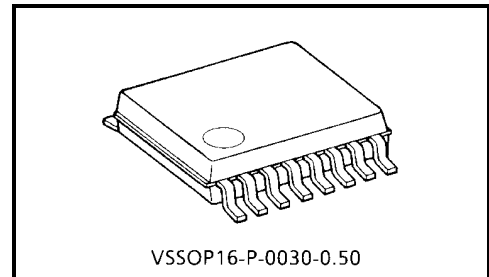
Weight: 0.02 g (typ.)

Features

- High speed: t_{pd} = 5.7 ns (typ.) (V_{CC} = 5 V)
- Low power dissipation: I_{CC} = 4 μA (max) (Ta = 25°C)
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC\ (opr)}$ = 2~5.5 V
- Pin and function compatible with 74ALS138

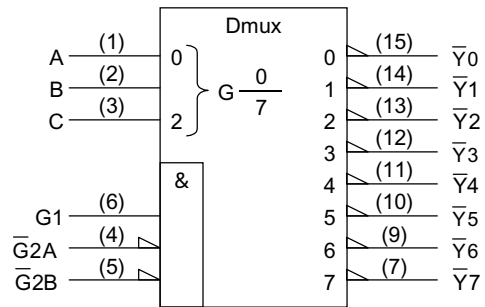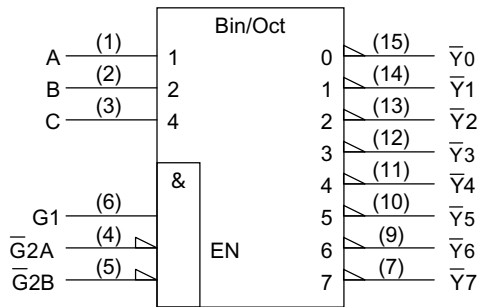000630EBA1

Pin Assignment (top view)

A	1	16	V_{CC}
B	2	15	$\overline{Y}0$
C	3	14	$\overline{Y}1$
$\overline{G}2A$	4	13	$\overline{Y}2$
$\overline{G}2B$	5	12	$\overline{Y}3$
G1	6	11	$\overline{Y}4$
$\overline{Y}7$	7	10	$\overline{Y}5$
GND	8	9	$\overline{Y}6$

IEC Logic Symbol

Bin/Oct

A (1)	1	0 (15)	$\overline{Y}0$
B (2)	2	1 (14)	$\overline{Y}1$
C (3)	4	2 (13)	$\overline{Y}2$
		3 (12)	$\overline{Y}3$
		4 (11)	$\overline{Y}4$
G1 (6)		5 (10)	$\overline{Y}5$
$\overline{G}2A$ (4)	EN	6 (9)	$\overline{Y}6$
$\overline{G}2B$ (5)		7 (7)	$\overline{Y}7$

Dmux

A (1)	0	0 (15)	$\overline{Y}0$
B (2)	G	1 (14)	$\overline{Y}1$
C (3)	2 ⎬ 0/7	2 (13)	$\overline{Y}2$
		3 (12)	$\overline{Y}3$
		4 (11)	$\overline{Y}4$
G1 (6)		5 (10)	$\overline{Y}5$
$\overline{G}2A$ (4)		6 (9)	$\overline{Y}6$
$\overline{G}2B$ (5)		7 (7)	$\overline{Y}7$

Truth Table

Inputs						Outputs								Selected Output
Enable			Select			$\overline{Y}0$	$\overline{Y}1$	$\overline{Y}2$	$\overline{Y}3$	$\overline{Y}4$	$\overline{Y}5$	$\overline{Y}6$	$\overline{Y}7$	
G1	$\overline{G}2A$	$\overline{G}2B$	C	B	A									
L	X	X	X	X	X	H	H	H	H	H	H	H	H	None
X	H	X	X	X	X	H	H	H	H	H	H	H	H	None
X	X	H	X	X	X	H	H	H	H	H	H	H	H	None
H	L	L	L	L	L	L	H	H	H	H	H	H	H	$\overline{Y}0$
H	L	L	L	L	H	H	L	H	H	H	H	H	H	$\overline{Y}1$
H	L	L	L	H	L	H	H	L	H	H	H	H	H	$\overline{Y}2$
H	L	L	L	H	H	H	H	H	L	H	H	H	H	$\overline{Y}3$
H	L	L	H	L	L	H	H	H	H	L	H	H	H	$\overline{Y}4$
H	L	L	H	L	H	H	H	H	H	H	L	H	H	$\overline{Y}5$
H	L	L	H	H	L	H	H	H	H	H	H	L	H	$\overline{Y}6$
H	L	L	H	H	H	H	H	H	H	H	H	H	L	$\overline{Y}7$

X: Don't care

Logic Diagram
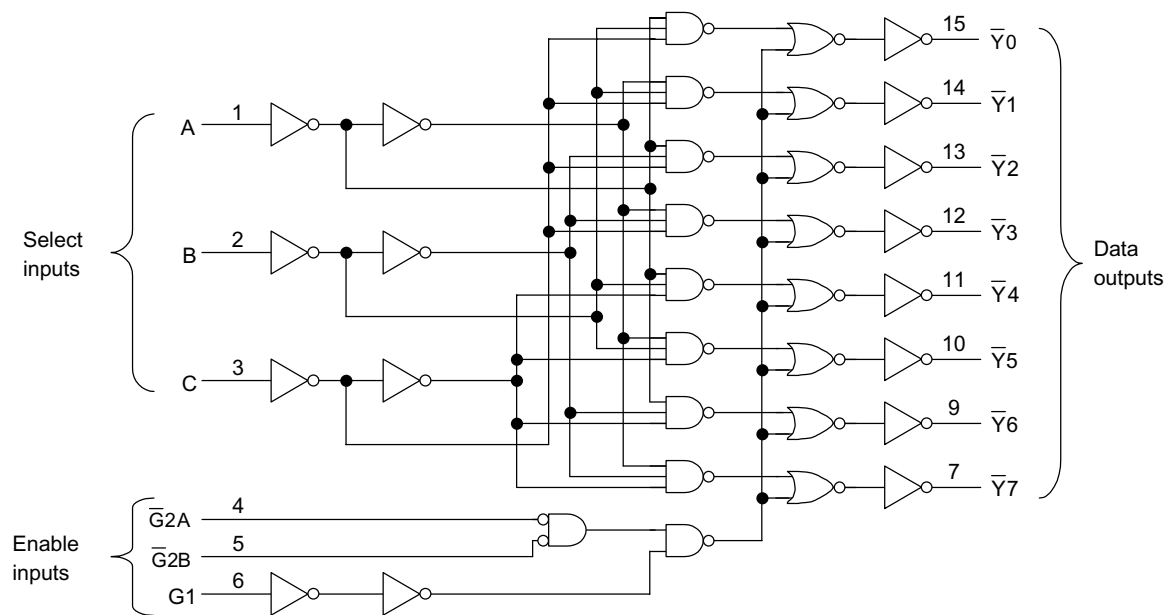
Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5~7.0	V
DC input voltage	V_{IN}	−0.5~7.0	V
DC output voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65~150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~V_{CC}	V
Operating temperature	T_{opr}	−40~85	°C
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 ± 0.3 V) 0~20 (V_{CC} = 5 ± 0.5 V)	ns/V

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		V_{CC} (V)	Ta = 25°C			Ta = −40~85°C		Unit
						Min	Typ.	Max	Min	Max	
Input voltage	High level	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
					3.0~5.5	$V_{CC} \times 0.7$	—	—	$V_{CC} \times 0.7$	—	
	Low level	V_{IL}	—		2.0	—	—	0.50	—	0.50	
					3.0~5.5	—	—	$V_{CC} \times 0.3$	—	$V_{CC} \times 0.3$	
Output voltage	High level	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50$ μA	2.0	1.9	2.0	—	1.9	—	V
					3.0	2.9	3.0	—	2.9	—	
					4.5	4.4	4.5	—	4.4	—	
				$I_{OH} = -4$ mA	3.0	2.58	—	—	2.48	—	
				$I_{OH} = -8$ mA	4.5	3.94	—	—	3.80	—	
	Low level	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50$ μA	2.0	—	0	0.1	—	0.1	
					3.0	—	0	0.1	—	0.1	
					4.5	—	0	0.1	—	0.1	
				$I_{OL} = 4$ mA	3.0	—	—	0.36	—	0.44	
				$I_{OL} = 8$ mA	4.5	—	—	0.36	—	0.44	
Input leakage current		I_{IN}	V_{IN} = 5.5 V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current		I_{CC}	$V_{IN} = V_{CC}$ or GND		5.5	—	—	4.0	—	40.0	μA

AC Characteristics (Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V_{CC} (V)	C_L (pF)	Ta = 25°C			Ta = −40~85°C		Unit
					Min	Typ.	Max	Min	Max	
Propagation delay time (A, B, C-$\overline{Y}$)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	8.2	11.4	1.0	13.5	ns
				50	—	10.0	15.8	1.0	18.0	
			5.0 ± 0.5	15	—	5.7	8.1	1.0	9.5	
				50	—	7.2	10.1	1.0	11.5	
Propagation delay time (G1-$\overline{Y}$)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	8.1	12.8	1.0	15.0	ns
				50	—	10.6	16.3	1.0	18.5	
			5.0 ± 0.5	15	—	5.6	8.1	1.0	9.5	
				50	—	7.1	10.1	1.0	11.5	
Propagation delay time ($\overline{G2}$ - $\overline{Y}$)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	8.2	11.4	1.0	13.5	ns
				50	—	10.7	14.9	1.0	17.0	
			5.0 ± 0.5	15	—	5.8	8.1	1.0	9.5	
				50	—	7.3	10.1	1.0	11.5	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Power dissipation capacitance	C_{PD}	(Note)			—	34	—	—	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

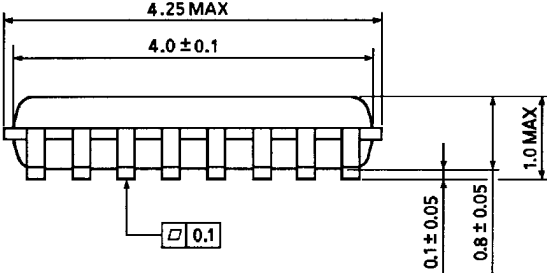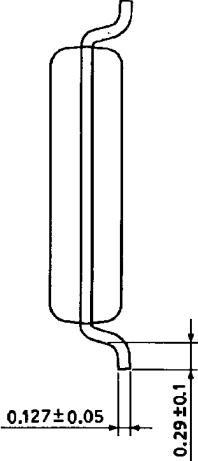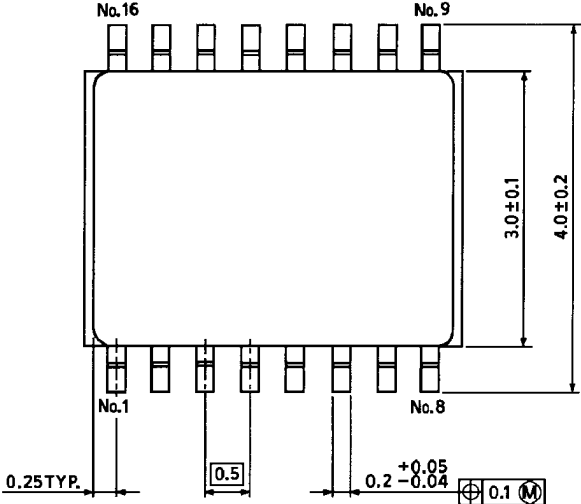$$I_{CC\,(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Input Equivalent Circuit
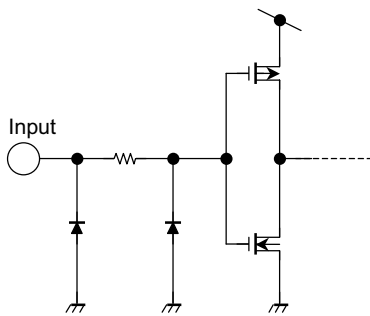
Package Dimensions

VSSOP16-P-0030-0.50   Unit : mm

No.16   No.9

3.0±0.1

4.0±0.2

No.1   No.8

0.25 TYP.   0.5   0.2 +0.05 −0.04   ⊕ 0.1 Ⓜ

0.127±0.05   0.29±0.1

4.25 MAX

4.0±0.1

1.0 MAX

▱ 0.1   0.1±0.05   0.8±0.05

Weight: 0.02 g (typ.)